

### **Features**

- Low R<sub>DS(on)</sub> & FOM
- · Extremely Low Switching Loss
- · Excellent Stability and Uniformity
- · Fast Switching and Soft Recovery
- Halogen Free. "Green" Device (Note 1)
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **Maximum Ratings**

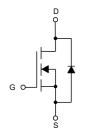
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 0.61°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Volltage	V <sub>GS</sub>	±20	V
Continuous Drain Current (2)	I <sub>D</sub>	75	Α
Pulsed Drain Current (3)	I <sub>DM</sub>	280	Α
Total Power Dissipation	P <sub>D</sub>	205	W
Single Pulsed Avalanche Energy <sup>(4)</sup>	E <sub>AS</sub>	200	mJ

#### Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The maximum current rating is package limited.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4.  $V_{DD}$ =50V,  $R_G$ =25 $\Omega$ , L=0.5mH, starting  $T_J$ =25 °C.

# **Internal Structure and Marking Code**

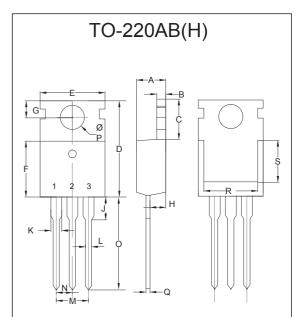


1. Gate 2. Drain

3. Source



# N-CHANNEL MOSFET



DIMENSIONS					
DIM	INCHES		MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.172	0.188	4.37	4.77	
В	0.049	0.057	1.25	1.45	
C	0.246	0.270	6.25	6.85	
D	0.594	0.634	15.10	16.10	
Е	0.382	0.406	9.70	10.30	
F	0.346	0.370	8.80	9.40	
G	0.102	0.118	2.60	3.00	
Η	0.087	0.102	2.20	2.60	
J		0.134		3.40	
K	0.046	0.058	1.17	1.47	
L	0.028	0.037	0.70	0.95	
М	0.200		5.	80	TYP.
Ν	0.100		2.	54	TYP.
0	0.502	0.543	12.75	13.80	
Р	0.134	0.150	3.40	3.80	Ф
Q	0.016	0.026	0.40	0.65	
R	0.276		7.00		
S	0.217		5.50		

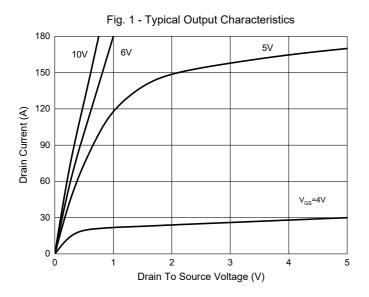


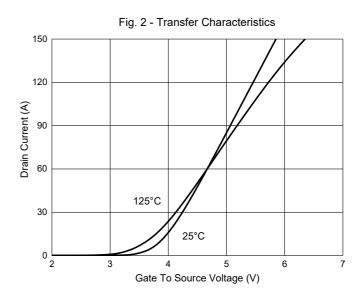
# Electrical Characteristics @ 25°C (Unless Otherwise Specified)

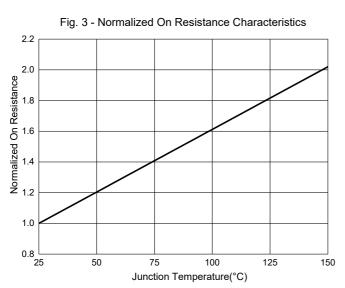
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics			'				
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	100			V	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =±20V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V			1	μA	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	2.8	4	V	
		V <sub>GS</sub> =10V, I <sub>D</sub> =20A		7.2	8.6	mΩ	
Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =6V, I <sub>D</sub> =20A		10	13	mΩ	
Gate Resistance	R <sub>G</sub>	f=1MHz, Open drain		0.68		Ω	
Diode Characteristics			'				
Continuous Body Diode Current	Is				75	Α	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =20A			1.3	V	
Reverse Recovery Time	t <sub>rr</sub>	1 004 1774 40047		51.5		ns	
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>S</sub> =20A,di/dt=100A/μs		84		nC	
Dynamic Characteristics			·				
Input Capacitance	C <sub>iss</sub>			2270			
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,f=1MHz		797		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			36		1	
Total Gate Charge	Qg			32			
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =10V,I <sub>D</sub> =25A		11.1		nC	
Gate-Drain Charge	$Q_{gd}$			4.78			
Turn-On Delay Time	t <sub>d(on)</sub>			51			
Turn-On Rise Time	t <sub>r</sub>	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V,		14.4		<b></b>	
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_G$ =2.2 $\Omega$ , $I_D$ =25A		69.2		ns	
Turn-Off Fall Time	t <sub>f</sub>			20.6			

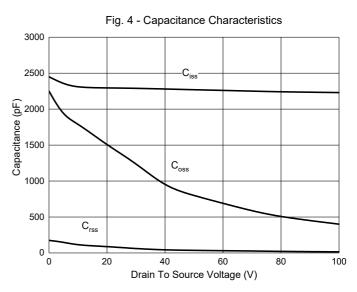


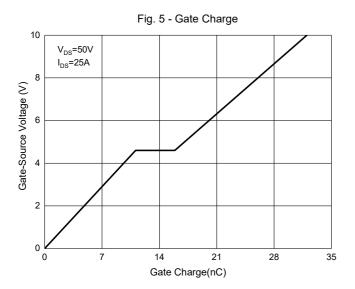
### **Curve Characteristics**

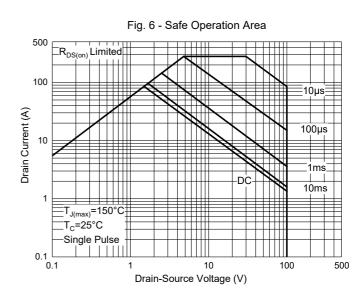














### **Ordering Information**

Device	Packing	
Part Number-BP	Bulk:50pcs/Tube,1Kpcs/Box,5Kpcs/Carton	

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